

55 ns with power dissipation of just 275 mW over the commercial temperature range. When the device is deselected, the CMOS standby current is less than 100  $\mu$ A. For the AT49F001N(T) pin 1 for the DIP and PLCC packages and pin 9 for the TSOP package are don't connect pins.

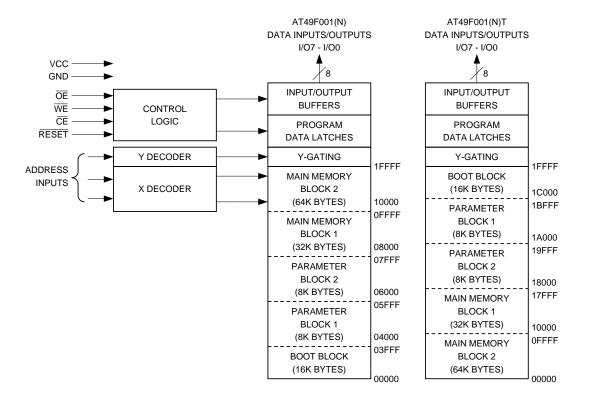
To allow for simple in-system reprogrammability, the AT49F001(N)(T) does not require high input voltages for programming. Five-volt-only commands determine the read and programming operation of the device. Reading data out of the device is similar to reading from an EPROM; it has standard  $\overline{CE}$ ,  $\overline{OE}$ , and  $\overline{WE}$  inputs to avoid bus contention. Reprogramming the AT49F001(N)(T) is performed by erasing a block of data and then programming on a byte-by-byte basis. The byte programming time is a fast 50  $\mu$ s. The end of a program cycle can be optionally detected by the  $\overline{DATA}$  polling feature. Once the end of a byte program cycle has been detected, a new access for a read or program can begin. The typical number of program and erase cycles is in excess of 10,000 cycles.

The device is erased by executing the erase command sequence; the device internally controls the erase operations. There are two 8K bytes parameter block sections and two main memory blocks.

The device has the capability to protect the data in the boot block; this feature is enabled by a command sequence. The 16-Kbyte boot block section includes a reprogramming lock out feature to provide data integrity. The boot sector is designed to contain user secure code, and when the feature is enabled, the boot sector is protected from being reprogrammed.

In the AT49F001(N)(T), once the boot block programming lockout feature is enabled, the contents of the boot block are permanent and cannot be changed. In the AT49F001(T), once the boot block programming lockout feature is enabled, the contents of the boot block cannot be changed with input voltage levels of 5.5 volts or less.

## **Block Diagram**



2

# Device Operation

**READ:** The AT49F001(N)(T) is accessed like an EPROM. When  $\overline{\text{CE}}$  and  $\overline{\text{OE}}$  are low and  $\overline{\text{WE}}$  is high, the data stored at the memory location determined by the address pins is asserted on the outputs. The outputs are put in the high impedance state whenever  $\overline{\text{CE}}$  or  $\overline{\text{OE}}$  is high. This dual-line control gives designers flexibility in preventing bus contention.

**COMMAND SEQUENCES:** When the device is first powered on, it will be reset to the read or standby mode depending upon the state of the control line inputs. In order to perform other device functions, a series of command sequences are entered into the device. The command sequences are shown in the Command Definitions table. The command sequences are written by applying a low pulse on the  $\overline{\text{WE}}$  or  $\overline{\text{CE}}$  input with  $\overline{\text{CE}}$  or  $\overline{\text{WE}}$  low (respectively) and  $\overline{\text{OE}}$  high. The address is latched on the falling edge of  $\overline{\text{CE}}$  or  $\overline{\text{WE}}$ , whichever occurs last. The data is latched by the first rising edge of  $\overline{\text{CE}}$  or  $\overline{\text{WE}}$ . Standard microprocessor write timings are used. The address locations used in the command sequences are not affected by entering the command sequences.

**RESET**: A RESET input pin is provided to ease some system applications. When RESET is at a logic high level, the device is in its standard operating mode. A low level on the RESET input halts the present device operation and puts the outputs of the device in a high inpendance state. If the RESET pin makes a high-to-low transition during a program or erase operation, the operation may not be successfully completed and the operation will have to be repeated after a high level is applied to the RESET pin. When a high level is reasserted on the RESET pin, the device returns to the read or standby mode, depending upon the state of the control inputs. By applying a 12V  $\pm$  0.5V input signal to the RESET pin, the boot block array can be reprogrammed even if the boot block lockout feature has been enabled (see Boot Block Programming Lockout Override section). The RESET feature is not available for the AT49F001N(T).

**ERASURE:** Before a byte can be reprogrammed, the main memory block or parameter block which contains the byte must be erased. The erased state of the memory bits is a logical "1". The entire device can be erased at one time by using a 6-byte software code. The software chip erase code consists of 6-byte load commands to specific address locations with a specific data pattern (please refer to the Chip Erase Cycle Waveforms).

After the software chip erase has been initiated, the device will internally time the erase operation so that no external clocks are required. The maximum time needed to erase the whole chip is  $t_{\rm EC}$ . If the boot block lockout feature has been enabled, the data in the boot sector will not be erased.

**CHIP ERASE:** If the boot block lockout has been enabled, the Chip Erase function will erase Parameter Block 1, Parameter Block 2, Main Memory Block 1, and Main Memory Block 2 but not the boot block. If the Boot Block Lockout has not been enabled, the Chip Erase function will erase the entire chip. After the full chip erase the device will return back to read mode. Any command during chip erase will be ignored.





**SECTOR ERASE**: As an alternative to a full chip erase, the device is organized into sectors that can be individually erased. There are two 8-Kbyte parameter block sections and two main memory blocks. The 8-Kbyte parameter block sections can be independently erased and reprogrammed. The two main memory sections are designed to be used as alternative memory sectors. That is, whenever one of the blocks has been erased and reprogrammed, the other block should be erased and reprogrammed before the first block is again erased. The Sector Erase command is a six bus cycle operation. The sector address is latched on the falling  $\overline{\text{WE}}$  edge of the sixth cycle while the 30H data input command is latched at the rising edge of  $\overline{\text{WE}}$ . The sector erase starts after the rising edge of  $\overline{\text{WE}}$  of the sixth cycle. The erase operation is internally controlled; it will automatically time to completion.

**BYTE PROGRAMMING:** Once the memory array is erased, the device is programmed (to a logical "0") on a byte-by-byte basis. Please note that a data "0" cannot be programmed back to a "1"; only erase operations can convert "0"s to "1"s. Programming is accomplished via the internal device command register and is a 4 bus cycle operation (please refer to the Command Definitions table). The device will automatically generate the required internal program pulses.

The program cycle has addresses latched on the falling edge of  $\overline{\text{WE}}$  or  $\overline{\text{CE}}$ , whichever occurs last, and the data latched on the rising edge of  $\overline{\text{WE}}$  or  $\overline{\text{CE}}$ , whichever occurs first. Programming is completed after the specified  $t_{\text{BP}}$  cycle time. The  $\overline{\text{DATA}}$  polling feature may also be used to indicate the end of a program cycle.

**BOOT BLOCK PROGRAMMING LOCKOUT:** The device has one designated block that has a programming lockout feature. This feature prevents programming of data in the designated block once the feature has been enabled. The size of the block is 16K bytes. This block, referred to as the boot block, can contain secure code that is used to bring up the system. Enabling the lockout feature will allow the boot code to stay in the device while data in the rest of the device is updated. This feature does not have to be activated; the boot block's usage as a write protected region is optional to the user. The address range of the boot block is 00000 to 03FFF for the AT49F001(N) while the address range of the boot block is 1C000 to 1FFFF for the AT49F001(N)T.

Once the feature is enabled, the data in the boot block can no longer be erased or programmed with input voltage levels of 5.5V or less. Data in the main memory block can still be changed through the regular programming method. To activate the lockout feature, a series of six program commands to specific addresses with specific data must be performed. Please refer to the Command Definitions table.

**BOOT BLOCK LOCKOUT DETECTION:** A software method is available to determine if programming of the boot block section is locked out. When the device is in the software product identification mode (see Software Product Identification Entry and Exit sections) a read from address location 00002H will show if programming the boot block is locked out for the AT49F001(N) and a read from address 1C002H will show if programming the boot block is locked out for the AT49F001(N)T. If the data on I/O0 is low, the boot block can be programmed; if the data on I/O0 is high, the program lockout feature has been activated and the block cannot be programmed. The software product identification exit code should be used to return to standard operation.

BOOT BLOCK PROGRAMMING LOCKOUT OVERRIDE: The user can override the boot block programming lockout by taking the RESET pin to 12 volts. By doing this, protected boot block data can be altered through a chip erase, sector erase or word programming. When the RESET pin is brought back to TTL levels the boot block programming lockout feature is again active. This feature is not available on the AT49F001N(T).

**PRODUCT IDENTIFICATION:** The product identification mode identifies the device and manufacturer as Atmel. It may be accessed by hardware or software operation. The hardware operation mode can be used by an external programmer to identify the correct programming algorithm for the Atmel product.

For details, see Operating Modes (for hardware operation) or Software Product Identification. The manufacturer and device code is the same for both modes.

**DATA POLLING:** The AT49F001(N)(T) features  $\overline{\text{DATA}}$  polling to indicate the end of a program cycle. During a program cycle an attempted read of the last byte loaded will result in the complement of the loaded data on I/O7. Once the program cycle has been completed, true data is valid on all outputs and the next cycle may begin.  $\overline{\text{DATA}}$  polling may begin at any time during the program cycle.

**TOGGLE BIT:** In addition to DATA polling the AT49F001(N)(T) provides another method for determining the end of a program or erase cycle. During a program or erase operation, successive attempts to read data from the device will result in I/O6 toggling between one and zero. Once the program cycle has completed, I/O6 will stop toggling and valid data will be read. Examining the toggle bit may begin at any time during a program cycle.

**HARDWARE DATA PROTECTION:** Hardware features protect against inadvertent programs to the AT49F001(N)(T) in the following ways: (a)  $V_{CC}$  sense: if  $V_{CC}$  is below 3.8V (typical), the program function is inhibited. (b) Program inhibit: holding any one of  $\overline{OE}$  low,  $\overline{CE}$  high or  $\overline{WE}$  high inhibits program cycles. (c) Noise filter: pulses of less than 15 ns (typical) on the  $\overline{WE}$  or  $\overline{CE}$  inputs will not initiate a program cycle.





## Command Definition (in Hex)<sup>(1)</sup>

Command	Bus	1st Cy		2nd Cy		3rd Cy			Bus cle	5th Cy		6th Cy	Bus cle
Sequence	Cycles	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data
Read	1	Addr	D <sub>OUT</sub>										
Chip Erase	6	5555	AA	2AAA	55	5555	80	5555	AA	2AAA	55	5555	10
Sector Erase	6	5555	AA	2AAA	55	5555	80	5555	AA	2AAA	55	SA <sup>(4)</sup>	30
Byte Program	4	5555	AA	2AAA	55	5555	A0	Addr	D <sub>IN</sub>				
Boot Block Lockout <sup>(2)</sup>	6	5555	AA	2AAA	55	5555	80	5555	AA	2AAA	55	5555	40
Product ID Entry	3	5555	AA	2AAA	55	5555	90						
Product ID Exit <sup>(3)</sup>	3	5555	AA	2AAA	55	5555	F0						
Product ID Exit <sup>(3)</sup>	1	XXXX	F0										

- Notes: 1. The DATA FORMAT in each bus cycle is as follows: I/O7 I/O0 (Hex)
  - 2. The 16K byte boot sector has the address range 00000H to 03FFFH for the AT49F001(N) and 1C000H to 1FFFFH for the AT49F001(N)T.
  - 3. Either one of the Product ID Exit commands can be used.
  - 4. SA = sector addresses

For the AT49F001(N):

SA = 00000 to 03FFF for BOOT BLOCK

Nothing will happen and the device goes back to the read mode in 100 ns

SA = 04000 to 05FFF for PARAMETER BLOCK 1

SA = 06000 to 07FFF for PARAMETER BLOCK 2

SA = 08000 to 0FFFF for MAIN MEMORY ARRAY BLOCK 1

This command will erase - PB1, PB2 and MMB1

SA = 10000 to 1FFFF for MAIN MEMORY ARRAY BLOCK 2

For the AT49F001(N)T:

SA = 1C000 to 1FFFF for BOOT BLOCK

Nothing will happen and the device goes back to the read mode in 100 ns

SA = 1A000 to 1BFFF for PARAMETER BLOCK 1

SA = 18000 to 19FFF for PARAMETER BLOCK 2

SA = 10000 to 17FFF for MAIN MEMORY ARRAY BLOCK 1

This command will erase - PB1, PB2 and MMB1

SA = 00000 to 0FFFF for MAIN MEMORY ARRAY BLOCK 2

## Absolute Maximum Ratings\*

Absolute Maximum Ratings
Temperature Under Bias55°C to +125°C
Storage Temperature65°C to +150°C
All Input Voltages (including NC Pins) with Respect to Ground0.6V to +6.25V
All Output Voltages with Respect to Ground0.6V to V <sub>CC</sub> + 0.6V
Voltage on $\overline{\text{OE}}$ with Respect to Ground0.6V to +13.5V

\*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# **DC and AC Operating Range**

		AT49F001(N)(T)-55	AT49F001(N)(T)-70	AT49F001(N)(T)-90	AT49F001(N)(T)-12
Operating	Com.	0°C - 70°C	0°C - 70°C	0°C - 70°C	0°C - 70°C
Temperature (Case)	Ind.	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C
V <sub>CC</sub> Power Supply	·	5V ± 10%	5V ± 10%	5V ± 10%	5V ± 10%

## **Operating Modes**

Mode	CE	ΟE	WE	RESET <sup>(6)</sup>	Ai	1/0
Read	V <sub>IL</sub>	$V_{IL}$	V <sub>IH</sub>	V <sub>IH</sub>	Ai	D <sub>OUT</sub>
Program/Erase <sup>(2)</sup>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IL</sub>	V <sub>IH</sub>	Ai	D <sub>IN</sub>
Standby/Write Inhibit	V <sub>IH</sub>	X <sup>(1)</sup>	Х	V <sub>IH</sub>	Х	High Z
Program Inhibit	Х	Х	V <sub>IH</sub>	V <sub>IH</sub>		
Program Inhibit	Х	V <sub>IL</sub>	Х	V <sub>IH</sub>		
Output Disable	Х	V <sub>IH</sub>	Х	V <sub>IH</sub>		High Z
Reset	Х	Х	Х	V <sub>IL</sub>	X	High Z
Product Identification	·					
Handriana	.,		1/		A1 - A16 = V <sub>IL</sub> , A9 = V <sub>H</sub> , <sup>(3)</sup> A0 = V <sub>IL</sub>	Manufacturer Code <sup>(4)</sup>
Hardware	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>		A1 - A16 = V <sub>IL</sub> , A9 = V <sub>H</sub> , <sup>(3)</sup> A0 = V <sub>IH</sub>	Device Code <sup>(4)</sup>
0 - (5)					A0 = V <sub>IL</sub> , A1 - A16=V <sub>IL</sub>	Manufacturer Code <sup>(4)</sup>
Software <sup>(5)</sup>					A0 = V <sub>IH</sub> , A1 - A16=V <sub>IL</sub>	Device Code <sup>(4)</sup>

- Notes: 1. X can be  $V_{\rm IL}$  or  $V_{\rm IH}$ . 2. Refer to AC Programming Waveforms.
  - 3.  $V_H = 12.0V \pm 0.5V$ .
  - 4. Manufacturer Code: 1FH, Device Code: 05H AT49F001(N), 04H AT49F001(N)T
  - 5. See details under Software Product Identification Entry/Exit.
  - 6. This pin is not available on the AT49F001N(T).

## **DC Characteristics**

Symbol	Parameter	Condition	Condition			Units
I <sub>LI</sub>	Input Load Current	$V_{IN} = 0V \text{ to } V_{CC}$			10	μΑ
I <sub>LO</sub>	Output Leakage Current	$V_{I/O} = 0V \text{ to } V_{CC}$			10	μA
	V Standby Compatt CMCC	$\overline{\text{CE}} = \text{V}_{\text{CC}} - 0.3 \text{V to V}_{\text{CC}}$			100	μA
I <sub>SB1</sub>	V <sub>CC</sub> Standby Current CMOS	$CE = V_{CC} - 0.3V \text{ to } V_{CC}$	Ind.		300	μA
I <sub>SB2</sub>	V <sub>CC</sub> Standby Current TTL	$\overline{\text{CE}}$ = 2.0V to V <sub>CC</sub>	$\overline{\text{CE}}$ = 2.0V to V <sub>CC</sub>			mA
I <sub>CC</sub> <sup>(1)</sup>	V <sub>CC</sub> Active Current	f = 5 MHz; I <sub>OUT</sub> = 0 mA			50	mA
$V_{IL}$	Input Low Voltage				0.8	V
V <sub>IH</sub>	Input High Voltage			2.0		V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 2.1 mA	I <sub>OL</sub> = 2.1 mA			V
V <sub>OH1</sub>	Output High Voltage	I <sub>OH</sub> = -400 μA		2.4		V
V <sub>OH2</sub>	Output High Voltage CMOS	I <sub>OH</sub> = -100 μA; V <sub>CC</sub> = 4.5V		4.2		V

1. In the erase mode,  $\rm I_{\rm CC}$  is 90 mA. Note:

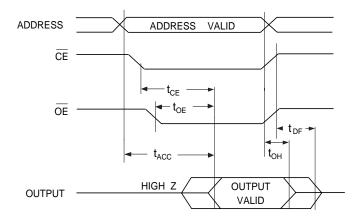




## **AC Read Characteristics**

		AT49F001(N)(T)-55		AT49F001(N)(T)-70		AT49F001(N)(T)-90		AT49F001(N)(T)-12		
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Units
t <sub>ACC</sub>	Address to Output Delay		55		70		90		120	ns
t <sub>CE</sub> <sup>(1)</sup>	CE to Output Delay		55		70		90		120	ns
t <sub>OE</sub> <sup>(2)</sup>	OE to Output Delay	0	30	0	35	0	40	0	50	ns
t <sub>DF</sub> <sup>(3)(4)</sup>	CE or OE to Output Float	0	25	0	25	0	25	0	30	ns
t <sub>OH</sub>	Output Hold from OE, CE or Address, whichever occurred first	0		0		0		0		ns

# AC Read Waveforms (1)(2)(3)(4)



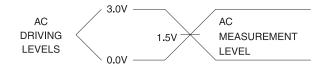
- Notes: 1.  $\overline{CE}$  may be delayed up to  $t_{ACC}$   $t_{CE}$  after the address transition without impact on  $t_{ACC}$ .

  2.  $\overline{OE}$  may be delayed up to  $t_{CE}$   $t_{OE}$  after the falling edge of  $\overline{CE}$  without impact on  $t_{CE}$  or by  $t_{ACC}$   $t_{OE}$  after an address change without impact on  $t_{ACC}$ .

  3.  $t_{DF}$  is specified from  $\overline{OE}$  or  $\overline{CE}$  whichever occurs first (CL = 5 pF).

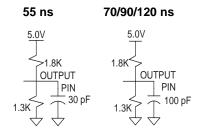
  - 4. This parameter is characterized and is not 100% tested.

# **Input Test Waveform and Measurement Level**



 $t_R$ ,  $t_F < 5$  ns

# **Output Load Test**



## **Pin Capacitance**

 $f = 1 \text{ MHz}, T = 25^{\circ}C^{(1)}$ 

Symbol	ol Typ Max		Units	Conditions
C <sub>IN</sub>	4	6	pF	$V_{IN} = 0V$
C <sub>OUT</sub>	8	12	pF	V <sub>OUT</sub> = 0V

Note: 1. This parameter is characterized and is not 100% tested.



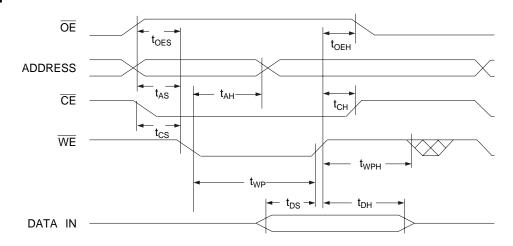


# **AC Byte Load Characteristics**

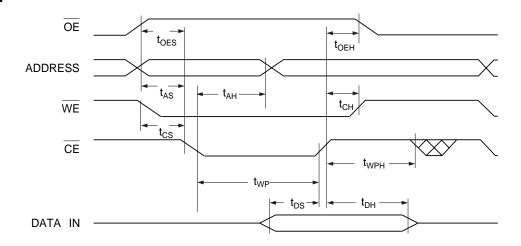
Symbol	Parameter	Min	Max	Units
t <sub>AS</sub> , t <sub>OES</sub>	Address, OE Set-up Time	0		ns
t <sub>AH</sub>	Address Hold Time	50		ns
t <sub>CS</sub>	Chip Select Set-up Time	0		ns
t <sub>CH</sub>	Chip Select Hold Time	0		ns
t <sub>WP</sub>	Write Pulse Width (WE or CE)	90		ns
t <sub>DS</sub>	Data Set-up Time	50		ns
t <sub>DH</sub> , t <sub>OEH</sub>	Data, $\overline{\text{OE}}$ Hold Time	0		ns
t <sub>WPH</sub>	Write Pulse Width High	90		ns

# **AC Byte Load Waveforms**

## **WE** Controlled



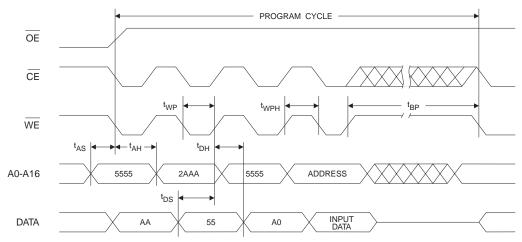
## **CE** Controlled



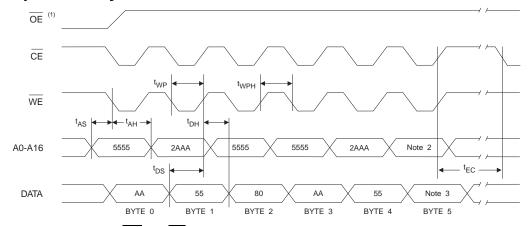
## **Program Cycle Characteristics**

Symbol	Parameter	Min	Тур	Max	Units
t <sub>BP</sub>	Byte Programming Time		10	50	μs
t <sub>AS</sub>	Address Set-up Time	0			ns
t <sub>AH</sub>	Address Hold Time	50			ns
t <sub>DS</sub>	Data Set-up Time	50			ns
t <sub>DH</sub>	Data Hold Time	0			ns
t <sub>WP</sub>	Write Pulse Width	90			ns
t <sub>WPH</sub>	Write Pulse Width High	90			ns
t <sub>EC</sub>	Erase Cycle Time			10	seconds

# **Program Cycle Waveforms**



# **Sector or Chip Erase Cycle Waveforms**



Notes: 1.  $\overline{OE}$  must be high only when  $\overline{WE}$  and  $\overline{CE}$  are both low.

- 2. For chip erase, the address should be 5555. For sector erase, the address depends on what sector is to be erased. (See note 4 under command definitions.)
- 3. For chip erase, the data should be 10H, and for sector erase, the data should be 30H.





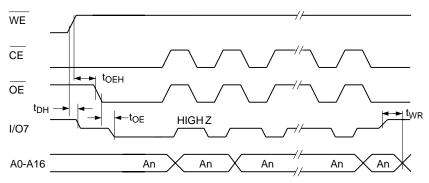
# **Data** Polling Characteristics<sup>(1)</sup>

Symbol	Parameter	Min	Тур	Max	Units
t <sub>DH</sub>	Data Hold Time	10			ns
t <sub>OEH</sub>	OE Hold Time	10			ns
t <sub>OE</sub>	ŌĒ to Output Delay <sup>(2)</sup>				ns
t <sub>WR</sub>	Write Recovery Time	0			ns

Notes: 1. These parameters are characterized and not 100% tested.

2. See  $t_{\text{OE}}$  spec in AC Read Characteristics.

## **Data** Polling Waveforms



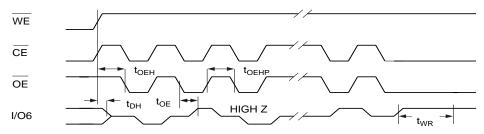
# Toggle Bit Characteristics(1)

Symbol	Parameter	Min	Тур	Max	Units
t <sub>DH</sub>	Data Hold Time	10			ns
t <sub>OEH</sub>	OE Hold Time	10			ns
t <sub>OE</sub>	$\overline{OE}$ to Output Delay <sup>(2)</sup>				ns
t <sub>OEHP</sub>	OE High Pulse	150			ns
t <sub>WR</sub>	Write Recovery Time	0			ns

Notes: 1. These parameters are characterized and not 100% tested.

2. See  $t_{\text{OE}}$  spec in AC Read Characteristics.

# Toggle Bit Waveforms<sup>(1)(2)(3)</sup>



Notes: 1. Toggling either  $\overline{OE}$  or  $\overline{CE}$  or both  $\overline{OE}$  and  $\overline{CE}$  will operate toggle bit. The t<sub>OEHP</sub> specification must be met by the toggling input(s).

2. Beginning and ending state of I/O6 will vary.

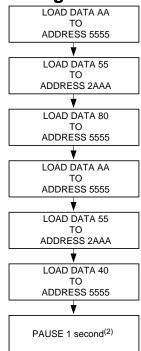
3. Any address location may be used but the address should not vary.

# 12 AT49F001(N(T)

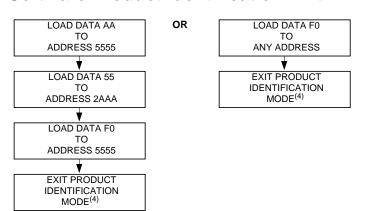
## **Software Product Identification Entry**<sup>(1)</sup>

# LOAD DATA AA TO ADDRESS 5555 LOAD DATA 55 TO ADDRESS 2AAA LOAD DATA 90 TO ADDRESS 5555 ENTER PRODUCT IDENTIFICATION MODE(2)(3)(5)

# **Boot Block Lockout Feature Enable Algorithm**(1)



## **Software Product Identification Exit<sup>(1)</sup>**



Notes: 1. Data Format: I/O7 - I/O0 (Hex); Address Format: A14 - A0 (Hex).

2. Boot block lockout feature enabled.

- Notes: 1. Data Format: I/O7 I/O0 (Hex); Address Format: A14 - A0 (Hex).
  - 2. A1 A16 =  $V_{IL}$ . Manufacture Code is read for A0 =  $V_{IL}$ ; Device Code is read for A0 =  $V_{IH}$ .
  - The device does not remain in identification mode if powered down.
  - 4. The device returns to standard operation mode.
  - Manufacturer Code: 1FH
     Device Code: 05H AT49F001(N)
     04H AT49F001(N)T





# **AT49F001 Ordering Information**

t <sub>ACC</sub>	I <sub>cc</sub> (	(mA)			
(ns)	Active	Standby	Ordering Code	Package	Operation Range
55	50	0.1	AT49F001-55JC	32J	Commercial
			AT49F001-55PC	32P6	(0° to 70°C)
			AT49F001-55TC	32T	
			AT49F001-55VC	32V	
	50	0.3	AT49F001-55JI	32J	Industrial
			AT49F001-55PI	32P6	(-40° to 85°C)
			AT49F001-55TI	32T	
			AT49F001-55VI	32V	
70	50	0.1	AT49F001-70JC	32J	Commercial
			AT49F001-70PC	32P6	(0° to 70°C)
			AT49F001-70TC	32T	
			AT49F001-70VC	32V	
	50	0.3	AT49F001-70JI	32J	Industrial
			AT49F001-70PI	32P6	(-40° to 85°C)
			AT49F001-70TI	32T	
			AT49F001-70VI	32V	
90	50	0.1	AT49F001-90JC	32J	Commercial
			AT49F001-90PC	32P6	(0° to 70°C)
			AT49F001-90TC	32T	
			AT49F001-90VC	32V	
	50	0.3	AT49F001-90JI	32J	Industrial
			AT49F001-90PI	32P6	(-40° to 85°C)
			AT49F001-90TI	32T	
			AT49F001-90VI	32V	
120	50	0.1	AT49F001-12JC	32J	Commercial
			AT49F001-12PC	32P6	(0° to 70°C)
			AT49F001-12TC	32T	
			AT49F001-12VC	32V	
	50	0.3	AT49F001-12JI	32J	Industrial
			AT49F001-12PI	32P6	(-40° to 85°C)
			AT49F001-12TI	32T	
			AT49F001-12VI	32V	

Package Type				
32J	32-lead, Plastic, J-leaded Chip Carrier Package (PLCC)			
32P6	32-lead, 0.600" Wide, Plastic Dual In-line Package (PDIP)			
32T	32-lead, Plastic Thin Small Outline Package (TSOP)			
32V	32-lead, Plastic Thin Small Outline Package (VSOP) (8 x 14 mm)			

# **AT49F001N Ordering Information**

t <sub>ACC</sub>	I <sub>CC</sub> (mA)				
(ns)	Active	Standby	Ordering Code	Package	Operation Range
55	5 50 0.1		AT49F001N-55JC	32J	Commercial
			AT49F001N-55PC	32P6	(0° to 70°C)
			AT49F001N-55TC 32T		
			AT49F001N-55VC	32V	
	50	0.3	AT49F001N-55JI	32J	Industrial
			AT49F001N-55PI	32P6	(-40° to 85°C)
			AT49F001N-55TI	32T	
			AT49F001N-55VI	32V	
70	50	0.1	AT49F001N-70JC	32J	Commercial
			AT49F001N-70PC	32P6	(0° to 70°C)
			AT49F001N-70TC	32T	
			AT49F001N-70VC	32V	
	50	0.3	AT49F001N-70JI	32J	Industrial
	μ μ		AT49F001N-70PI	32P6	(-40° to 85°C)
			AT49F001N-70TI	32T	
			AT49F001N-70VI	32V	
90	50	0.1	AT49F001N-90JC	32J	Commercial
			AT49F001N-90PC 32P6		(0° to 70°C)
			AT49F001N-90TC 32T		
			AT49F001N-90VC 32V		
	50	0.3	AT49F001N-90JI	32J	Industrial
			AT49F001N-90PI	32P6	(-40° to 85°C)
			AT49F001N-90TI	32T	
			AT49F001N-90VI	32V	
120	50	0.1	AT49F001N-12JC	32J	Commercial
			AT49F001N-12PC	32P6	(0° to 70°C)
			AT49F001N-12TC	32T	
			AT49F001N-12VC	32V	
	50 0.3 AT49F001N-12JI		AT49F001N-12JI	32J	Industrial
			AT49F001N-12PI 32P6 (-		(-40° to 85°C)
			AT49F001N-12TI 32T		
			AT49F001N-12VI	32V	

	Package Type				
32J	32-lead, Plastic, J-leaded Chip Carrier Package (PLCC)				
32P6	32-lead, 0.600" Wide, Plastic Dual In-line Package (PDIP)				
32T	32-lead, Plastic Thin Small Outline Package (TSOP)				
32V	32-lead, Plastic Thin Small Outline Package (VSOP) (8 x 14 mm)				





# **AT49F001T Ordering Information**

t <sub>ACC</sub>	I <sub>cc</sub> (	(mA)			
(ns)	Active	Standby	Ordering Code	Package	Operation Range
55	55 50 0.1		AT49F001T-55JC	32J	Commercial
			AT49F001T-55PC	32P6	(0° to 70°C)
			AT49F001T-55TC	32T	
			AT49F001T-55VC	32V	
	50	0.3	AT49F001T-55JI	32J	Industrial
			AT49F001T-55PI	32P6	(-40° to 85°C)
			AT49F001T-55TI	32T	
			AT49F001T-55VI	32V	
70	50	0.1	AT49F001T-70JC	32J	Commercial
			AT49F001T-70PC	32P6	(0° to 70°C)
			AT49F001T-70TC	32T	
			AT49F001T-70VC	32V	
	50	0.3	AT49F001T-70JI	32J	Industrial
		AT49F001T-70PI		32P6	(-40° to 85°C)
			AT49F001T-70TI	32T	
			AT49F001T-70VI	32V	
90	50	0.1	AT49F001T-90JC	32J	Commercial
			AT49F001T-90PC 32P6		(0° to 70°C)
			AT49F001T-90TC	32T	
			AT49F001T-90VC	32V	
	50	0.3	AT49F001T-90JI	32J	Industrial
			AT49F001T-90PI	32P6	(-40° to 85°C)
			AT49F001T-90TI	32T	
			AT49F001T-90VI	32V	
120	50	0.1	AT49F001T-12JC	32J	Commercial
			AT49F001T-12PC	32P6	(0° to 70°C)
			AT49F001T-12TC	32T	
			AT49F001T-12VC	32V	
	50	0.3	AT49F001T-12JI	32J	Industrial
			AT49F001T-12PI	32P6	(-40° to 85°C)
			AT49F001T-12TI 32T		
			AT49F001T-12VI	32V	

Package Type					
32J	32-lead, Plastic, J-leaded Chip Carrier Package (PLCC)				
32P6	32-lead, 0.600" Wide, Plastic Dual Inline Package (PDIP)				
32T	32-lead, Plastic Thin Small Outline Package (TSOP)				
32V	32-lead, Plastic Thin Small Outline Package (VSOP) (8 x 14 mm)				

# AT49F001NT Ordering Information

t <sub>ACC</sub> (ns)	I <sub>CC</sub> (mA)		Ordering Code	Package	Operation Range
55	50	0.1	AT49F001NT-55JC	32J	Commercial
			AT49F001NT-55PC	32P6	(0° to 70°C)
			AT49F001NT-55TC	32T	
			AT49F001NT-55VC	32V	
	50	0.3	AT49F001NT-55JI	32J	Industrial
			AT49F001NT-55PI	32P6	(-40° to 85°C)
			AT49F001NT-55TI	32T	
			AT49F001NT-55VI	32V	
70	50	0.1	AT49F001NT-70JC	32J	Commercial
			AT49F001NT-70PC	32P6	(0° to 70°C)
			AT49F001NT-70TC	32T	
			AT49F001NT-70VC	32V	
	50	0.3	AT49F001NT-70JI	32J	Industrial
			AT49F001NT-70PI	32P6	(-40° to 85°C)
			AT49F001NT-70TI	32T	
			AT49F001NT-70VI	32V	
90	50	0.1	AT49F001NT-90JC	32J	Commercial
			AT49F001NT-90PC	32P6	(0° to 70°C)
			AT49F001NT-90TC	32T	
			AT49F001NT-90VC	32V	
	50	0.3	AT49F001NT-90JI	32J	Industrial
			AT49F001NT-90PI	32P6	(-40° to 85°C)
			AT49F001NT-90TI	32T	
			AT49F001NT-90VI	32V	
120	50	0.1	AT49F001NT-12JC	32J	Commercial
			AT49F001NT-12PC	32P6	(0° to 70°C)
			AT49F001NT-12TC	32T	
			AT49F001NT-12VC	32V	
	50	0.3	AT49F001NT-12JI	32J	Industrial
			AT49F001NT-12PI	32P6	(-40° to 85°C)
			AT49F001NT-12TI	32T	
			AT49F001NT-12VI	32V	

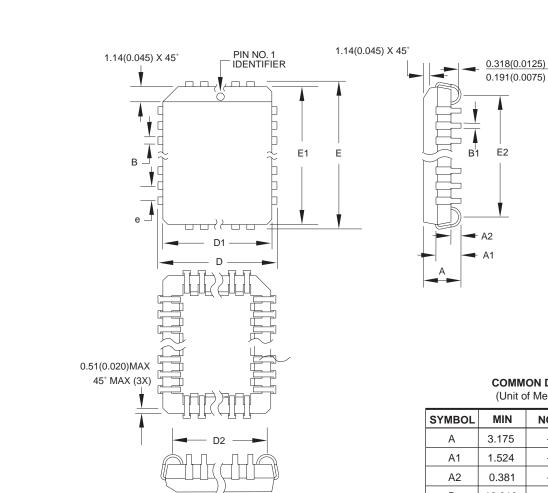
Package Type					
32J	32-lead, Plastic, J-leaded Chip Carrier Package (PLCC)				
32P6	32-lead, 0.600" Wide, Plastic Dual In-line Package (PDIP)				
32T	32-lead, Plastic Thin Small Outline Package (TSOP)				
32V	32-lead, Plastic Thin Small Outline Package (VSOP) (8 x 14 mm)				





# **Packaging Information**

## **32J - PLCC**



Notes:

- 1. This package conforms to JEDEC reference MS-016, Variation AE.
- 2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is .010"(0.254 mm) per side. Dimension D1 and E1 include mold mismatch and are measured at the extreme material condition at the upper or lower parting line.
- 3. Lead coplanarity is 0.004" (0.102 mm) maximum.

## **COMMON DIMENSIONS**

(Unit of Measure = mm)

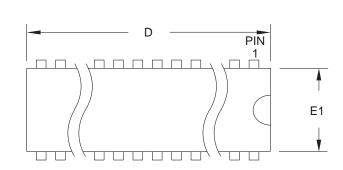
SYMBOL	MIN	NOM	MAX	NOTE			
Α	3.175	_	3.556				
A1	1.524	_	2.413				
A2	0.381	_	_				
D	12.319	_	12.573				
D1	11.354	_	11.506	Note 2			
D2	9.906	_	10.922				
Е	14.859	_	15.113				
E1	13.894	_	14.046	Note 2			
E2	12.471	_	13.487				
В	0.660	_	0.813				
B1	0.330	_	0.533				
е	1.270 TYP						

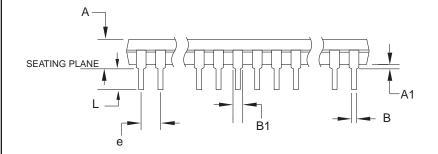
10/04/01

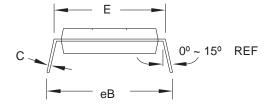
IIILE			
32J,	32-lead,	Plastic J-leaded	Chip Carrier (PLCC)

DRAWING NO.	RE\
32J	В

## 32P6 - PDIP







Note: 1. Dimensions D and E1 do not include mold Flash or Protrusion.

Mold Flash or Protrusion shall not exceed 0.25 mm (0.010").

## **COMMON DIMENSIONS**

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
А	_	_	4.826	
A1	0.381	_	_	
D	41.783	_	42.291	Note 1
E	15.240	_	15.875	
E1	13.462	_	13.970	Note 1
В	0.356	_	0.559	
B1	1.041	_	1.651	
L	3.048	_	3.556	
С	0.203	-	0.381	
eВ	15.494	_	17.526	
е	2.540 TYP			

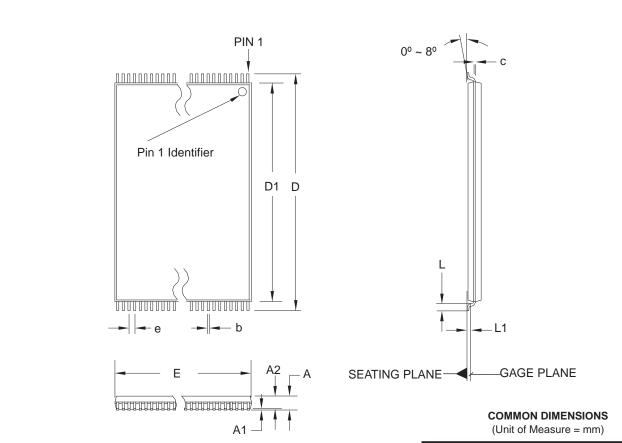
09/28/01

		DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	<b>32P6</b> , 32-lead (0.600"/15.24 mm Wide) Plastic Dual Inline Package (PDIP)	32P6	В





## **32T - TSOP**



Notes:

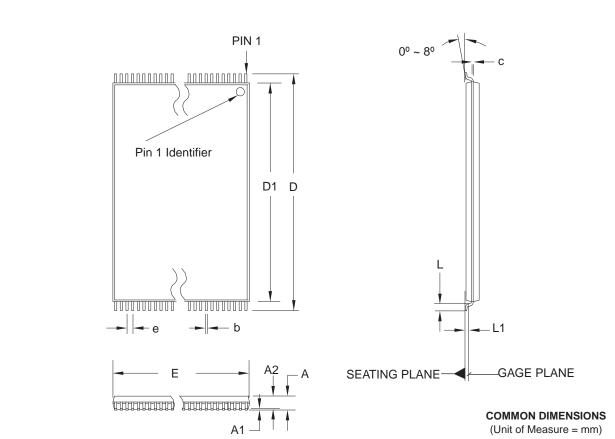
- 1. This package conforms to JEDEC reference MO-142, Variation BD.
- 2. Dimensions D1 and E do not include mold protrusion. Allowable protrusion on E is 0.15 mm per side and on D1 is 0.25 mm per side.
- 3. Lead coplanarity is 0.10 mm maximum.

(1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1				
SYMBOL	MIN	NOM	MAX	NOTE
Α	_	_	1.20	
A1	0.05	_	0.15	
A2	0.95	1.00	1.05	
D	19.80	20.00	20.20	
D1	18.30	18.40	18.50	Note 2
Е	7.90	8.00	8.10	Note 2
L	0.50	0.60	0.70	
L1	0.25 BASIC			
b	0.17	0.22	0.27	
С	0.10	_	0.21	
е	0.50 BASIC			
0.00 B/1010			l	

10/18/01

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	<b>32T</b> , 32-lead (8 x 20 mm Package) Plastic Thin Small Outline Package, Type I (TSOP)	32T	В

## **32V - VSOP**



Notes:

- 1. This package conforms to JEDEC reference MO-142, Variation BA.
- 2. Dimensions D1 and E do not include mold protrusion. Allowable protrusion on E is 0.15 mm per side and on D1 is 0.25 mm per side.
- 3. Lead coplanarity is 0.10 mm maximum.

Note 2
Note 2

10/18/01

		ITLE	DRAWING NO.	REV.
	nard Parkway CA 95131	<b>32V</b> , 32-lead (8 x 14 mm Package) Plastic Thin Small Outline Package, Type I (VSOP)	32V	В





## **Atmel Headquarters**

Corporate Headquarters 2325 Orchard Parkway San Jose, CA 95131 TEL 1(408) 441-0311 FAX 1(408) 487-2600

## Europe

Atmel Sarl Route des Arsenaux 41 Case Postale 80 CH-1705 Fribourg Switzerland TEL (41) 26-426-5555 FAX (41) 26-426-5500

## Asia

Room 1219 Chinachem Golden Plaza 77 Mody Road Tsimshatsui East Kowloon Hong Kong TEL (852) 2721-9778 FAX (852) 2722-1369

## Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 Japan TEL (81) 3-3523-3551 FAX (81) 3-3523-7581

## **Atmel Operations**

### Memory

2325 Orchard Parkway San Jose, CA 95131 TEL 1(408) 441-0311 FAX 1(408) 436-4314

#### Microcontrollers

2325 Orchard Parkway San Jose, CA 95131 TEL 1(408) 441-0311 FAX 1(408) 436-4314

La Chantrerie BP 70602 44306 Nantes Cedex 3, France TEL (33) 2-40-18-18-18 FAX (33) 2-40-18-19-60

## ASIC/ASSP/Smart Cards

Zone Industrielle 13106 Rousset Cedex, France TEL (33) 4-42-53-60-00 FAX (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 TEL 1(719) 576-3300 FAX 1(719) 540-1759

Scottish Enterprise Technology Park Maxwell Building East Kilbride G75 0QR, Scotland TEL (44) 1355-803-000 FAX (44) 1355-242-743

#### RF/Automotive

Theresienstrasse 2 Postfach 3535 74025 Heilbronn, Germany TEL (49) 71-31-67-0 FAX (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 TEL 1(719) 576-3300 FAX 1(719) 540-1759

Biometrics/Imaging/Hi-Rel MPU/ High Speed Converters/RF Datacom Avenue de Rochepleine BP 123 38521 Saint-Egreve Cedex, France TEL (33) 4-76-58-30-00 FAX (33) 4-76-58-34-80

e-mail literature@atmel.com

Web Site http://www.atmel.com

## © Atmel Corporation 2003.

Atmel Corporation makes no warranty for the use of its products, other than those expressly contained in the Company's standard warranty which is detailed in Atmel's Terms and Conditions located on the Company's web site. The Company assumes no responsibility for any errors which may appear in this document, reserves the right to change devices or specifications detailed herein at any time without notice, and does not make any commitment to update the information contained herein. No licenses to patents or other intellectual property of Atmel are granted by the Company in connection with the sale of Atmel products, expressly or by implication. Atmel's products are not authorized for use as critical components in life support devices or systems.

Atmel® is the registered trademark of Atmel.

Other terms and product names may be the trademarks of others.

